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VS-85EPF12 Soft Recovery Series

Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 85 A

Cathode Anode

PowerTab[®]

LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | |
|----------------------------------|-----------------------|--|--|--|
| I _{F(AV)} | 85 A | | | |
| V _R | 1200 V | | | |
| V _F at I _F | 1.36 V | | | |
| I _{FSM} | 1250 A | | | |
| t _{rr} | 95 ns | | | |
| T _J max. | 150 °C | | | |
| Snap factor | 0.5 | | | |
| Package | PowerTab [®] | | | |
| Circuit configuration | Single | | | |

FEATURES

- Glass passivated pellet chip junction
- 150 °C max. operating junction temperature
- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met
- Screw mounting only
- Designed and qualified according to JEDEC[®]-JESD 47
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-85EPF12 fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions. Available in the new PowerTab package, this new series is suitable for a large range of applications combining excellent die to footprint ratio and sturdiness connectivity for use in high current environments.

MECHANICAL DATA

Case: PowerTab®

Molding compound meets UL 94 V-0 flammability rating **Terminal:** nickel plated, screwable

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | |
|-----------------------------------|--|------------------------------|----|--|--|--|--|
| SYMBOL | CHARACTERISTICS | CHARACTERISTICS VALUES UNITS | | | | | |
| I _{F(AV)} | Rect. conduction 50 % duty cycle at $T_C = 85 \ ^{\circ}C$ | 85 | ۸ | | | | |
| I _{F(RMS)} | | 160 | A | | | | |
| V _{RRM} | | 1200 | V | | | | |
| I _{FSM} | | 1250 | А | | | | |
| V _F | 100 A, T _J = 25 °C | 1.4 | V | | | | |
| t _{rr} | 1 A, - 100 A/μs | 95 | ns | | | | |
| TJ | Range | -40 to +150 | °C | | | | |

| VOLTAGE RATINGS | | | |
|-----------------|---|--|-------------------------------------|
| TYPE NUMBER | V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} AT 150 °C mA |
| VS-85EPF12 | 1200 | 1300 | 15 |

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|---|--------------------|--|-----------------------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum average forward current | I _{F(AV)} | $T_C = 85 \text{ °C}, 180^\circ \text{ conduction half sine wave}$ | 85 | | |
| Maximum peak one cycle non-repetitive surge current | I _{FSM} | 10 ms sine pulse, rated V _{RRM} applied | 1100 | А | |
| Maximum peak one cycle non-repetitive surge current | | 10 ms sine pulse, no voltage reapplied | 1250 | | |
| Maximum I ² t for fusing | l ² t | 10 ms sine pulse, rated V _{RRM} applied | 5000 A ² s | | |
| | | 10 ms sine pulse, no voltage reapplied | 7000 | A-S | |
| Maximum I ² \sqrt{t} for fusing | l²√t | t = 0.1 ms to 10 ms, no voltage reapplied | 70 000 | A²√s | |

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|----|------|------|------|--------|-------------|

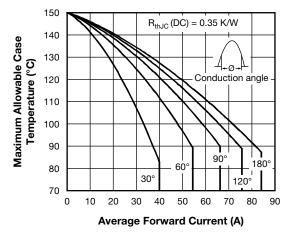
| ELECTRICAL SPECIFICATIONS | | | | | | |
|---------------------------------|--------------------|------------------------------|---|------|-------|--|
| PARAMETER | SYMBOL | TEST CO | TEST CONDITIONS | | UNITS | |
| Maximum forward voltage drop | V _{FM} | 85 A, T _J = 25 °C | | 1.36 | V | |
| Forward slope resistance | r _t | T _J = 150 °C | | 4.03 | mΩ | |
| Threshold voltage | V _{F(TO)} | | | 0.87 | V | |
| Maximum reverse leakage current | | T _J = 25 °C | V _B = Rated V _{BBM} | 0.1 | mA | |
| Maximum reverse leakage current | | T _J = 150 °C | VR - naieu VRRM | 15 | | |

| RECOVERY CHARACTERISTICS | | | | | | |
|--------------------------|-----------------|---|--------|-------|--------------------------------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Reverse recovery time | t _{rr} | In at 85 Anic | 480 | ns | I _{FM} t | |
| Reverse recovery current | I _{rr} | l _F at 85 A _{pk} 25 A/μs | 7.1 | А | | |
| Reverse recovery charge | Q _{rr} | 25 °C | 2.1 | μC | $\frac{\text{dir}}{\text{dt}}$ | |
| Snap factor | S | | 0.5 | | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | |
|---|---|-----------------------------------|--------------------------------------|-------------|------------|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum junction and s temperature range | torage | T _J , T _{Stg} | | -40 to +150 | °C |
| Maximum thermal resista junction to case | ance, | R _{thJC} | DC operation | 0.35 | |
| Maximum thermal resista junction to ambient | ance, | R _{thJA} | | 40 | °C/W |
| Typical thermal resistanc case to heatsink | æ, | R _{thCS} | Mounting surface, smooth and greased | 0.2 | |
| Approximate weight | | | | 6 | g |
| Approximate weight | | | | 0.21 | oz. |
| Mounting torque | minimum | | | 6 (5) | kgf · cm |
| Mounting torque | maximum | | | 12 (10) | (lbf ⋅ in) |
| Marking device | Iarking device Case style PowerTab [®] 85EPF12 | | PF12 | | |



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Fig. 1 - Current Rating Characteristics

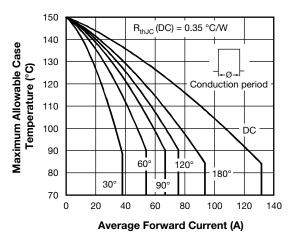


Fig. 2 - Current Rating Characteristics

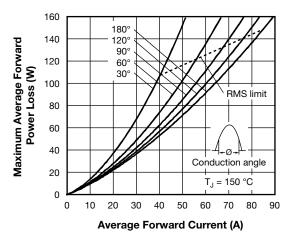


Fig. 3 - Forward Power Loss Characteristics

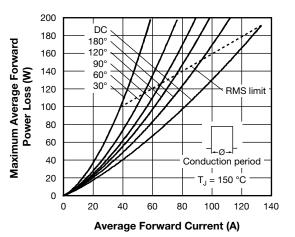
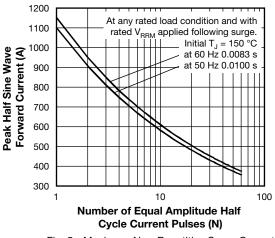
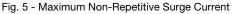


Fig. 4 - Forward Power Loss Characteristics





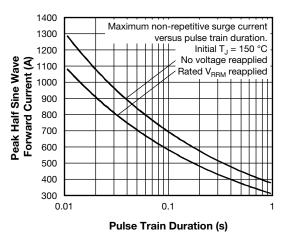


Fig. 6 - Maximum Non-Repetitive Surge Current

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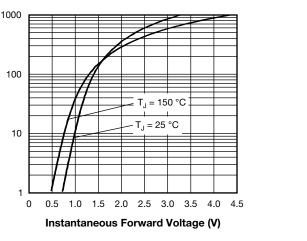


Fig. 7 - Forward Voltage Drop Characteristics

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Instantaneous Forward Current (A)

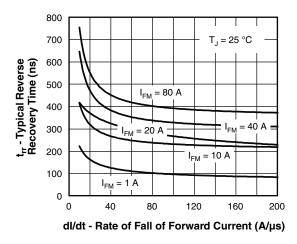


Fig. 8 - Recovery Time Characteristics, $T_J = 25 \ ^{\circ}C$

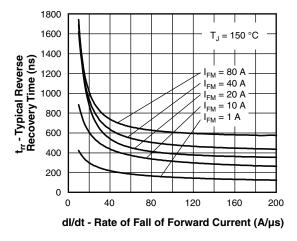


Fig. 9 - Recovery Time Characteristics, $T_J = 150 \ ^\circ C$

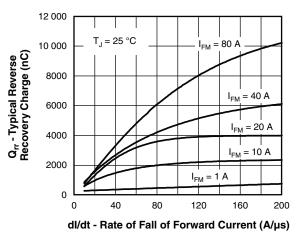


Fig. 10 - Recovery Charge Characteristics, $T_J = 25 \degree C$

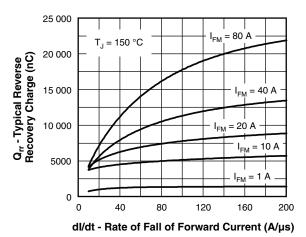


Fig. 11 - Recovery Charge Characteristics, $T_J = 150 \text{ }^{\circ}\text{C}$

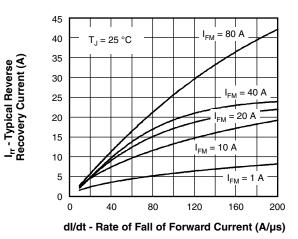


Fig. 12 - Recovery Current Characteristics, $T_J = 25$ °C

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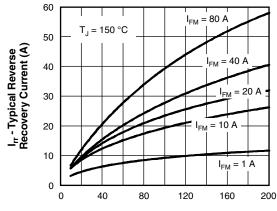
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dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

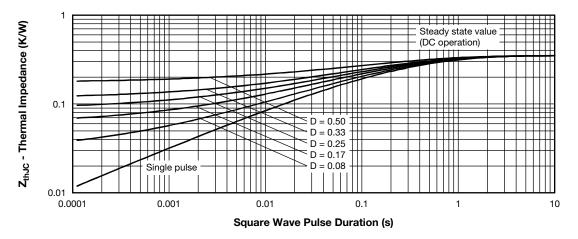


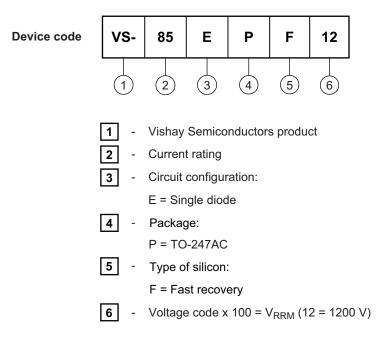
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics



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ORDERING INFORMATION TABLE



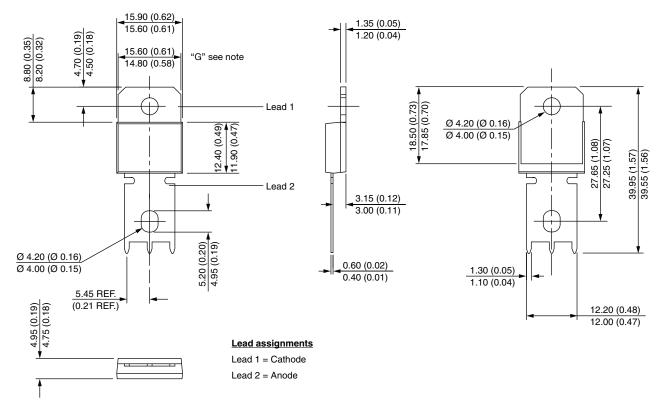
| LINKS TO RELATED DOCUMENTS | | | | |
|-------------------------------------|--------------------------|--|--|--|
| Dimensions www.vishay.com/doc?95240 | | | | |
| Part marking information | www.vishay.com/doc?95370 | | | |
| Application note | www.vishay.com/doc?95179 | | | |
| SPICE model | www.vishay.com/doc?96894 | | | |



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DIMENSIONS in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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